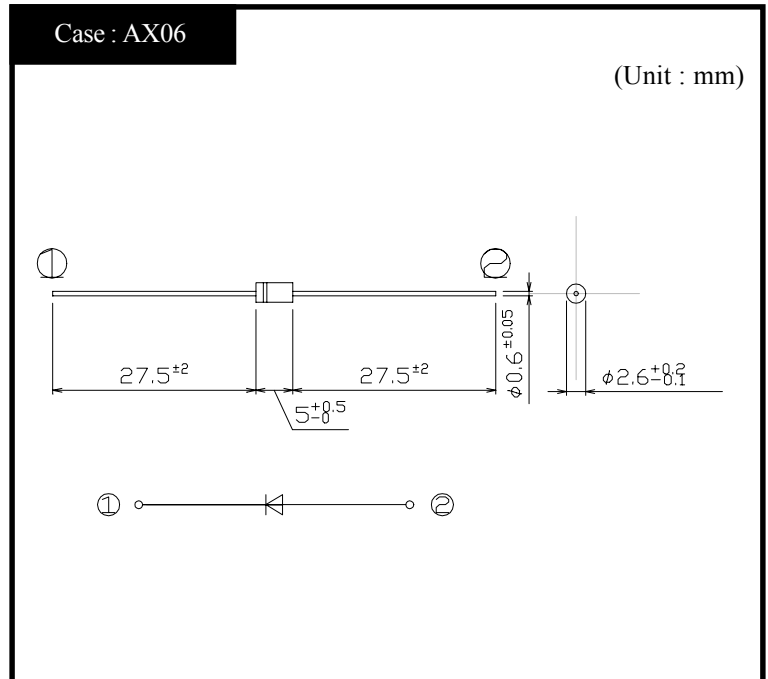


SHINDENGEN

Sidac

K1V(A)10

OUTLINE DIMENSIONS



RATINGS

● Absolute Maximum Ratings

Item	Symbol	Conditions	Ratings	Unit
Storage Temperature	T_{stg}		-40~125	°C
Operating Junction Temperature	T_j		125	°C
Maximum Off-state Voltage	V_{DRM}		90	V
RMS On-state Current	I_T	$T_l = 98^{\circ}C$, 50Hz sine wave ($\theta = 180^{\circ}$)	1	A
Surge On-state Current	I_{TSM}	$T_j = 25^{\circ}C$, 50Hz sine wave ($\theta = 180^{\circ}$), non-repetitive 1-cycle peak value	16	A
Pulse On-state Current	I_{TRM}	$T_a = 25^{\circ}C$, pulse width $t_o = 10 \mu s$, sine wave, repetitive peak value $f = 1 kHz$	15	A
		$T_a = 25^{\circ}C$, pulse width $t_o = 10 \mu s$, sine wave, repetitive peak value $f = 60 Hz$	60	
Critical Rate of Rise of On-state Current	di_T/dt		50	A/ μs

● Electrical Characteristics ($T_l=25^{\circ}C$)

Item	Symbol	Conditions	Ratings	Unit
Breakover Voltage	V_{BO}	$I_B = 0$, 50Hz sine wave	95~113	V
Off-state Current	I_{DRM}	$V_D = V_{DRM}$	Max 10	μA
Breakover Current	I_{BO}		Max 0.5	mA
Holding Current	I_H		TYP 50	mA
On-state Voltage	V_T	$I_T = 1A$	Max 1.6	V
Switching Resistance	R_S		Min 0.1	k Ω
Thermal Resistance	θ_{jl}	Junction to lead	Max 20	°C/W

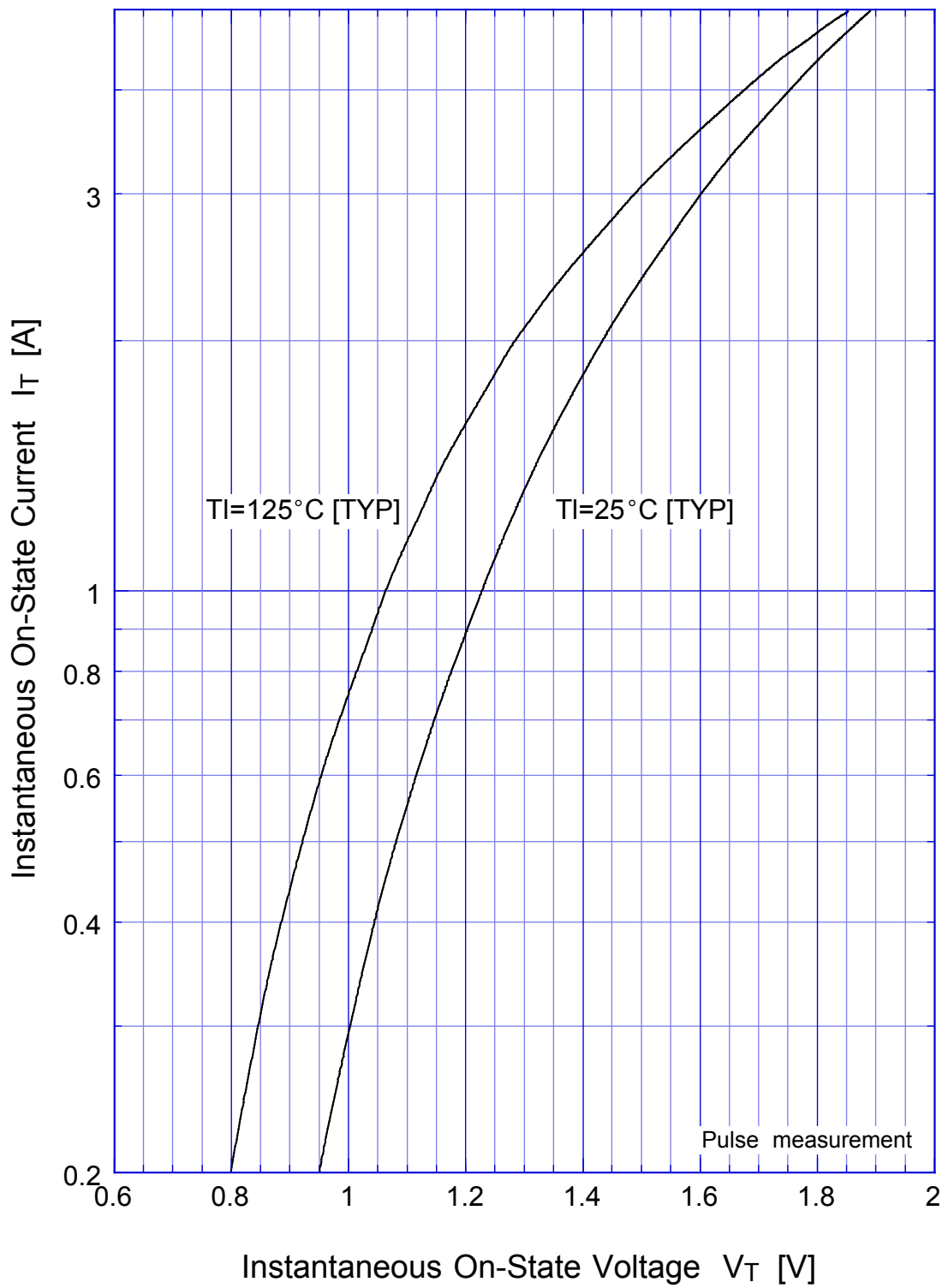
● Standard Design with P.C.B.

Item	Symbol	Conditions	Standard	Unit
RMS On-state Current	I_T	Assembled in P.C.B., $T_a = 25^{\circ}C$, soldering land 3mm ϕ	0.6	A

K1V(A)10

K1V(A)11

K1V(A)12 Typical On-State Voltage

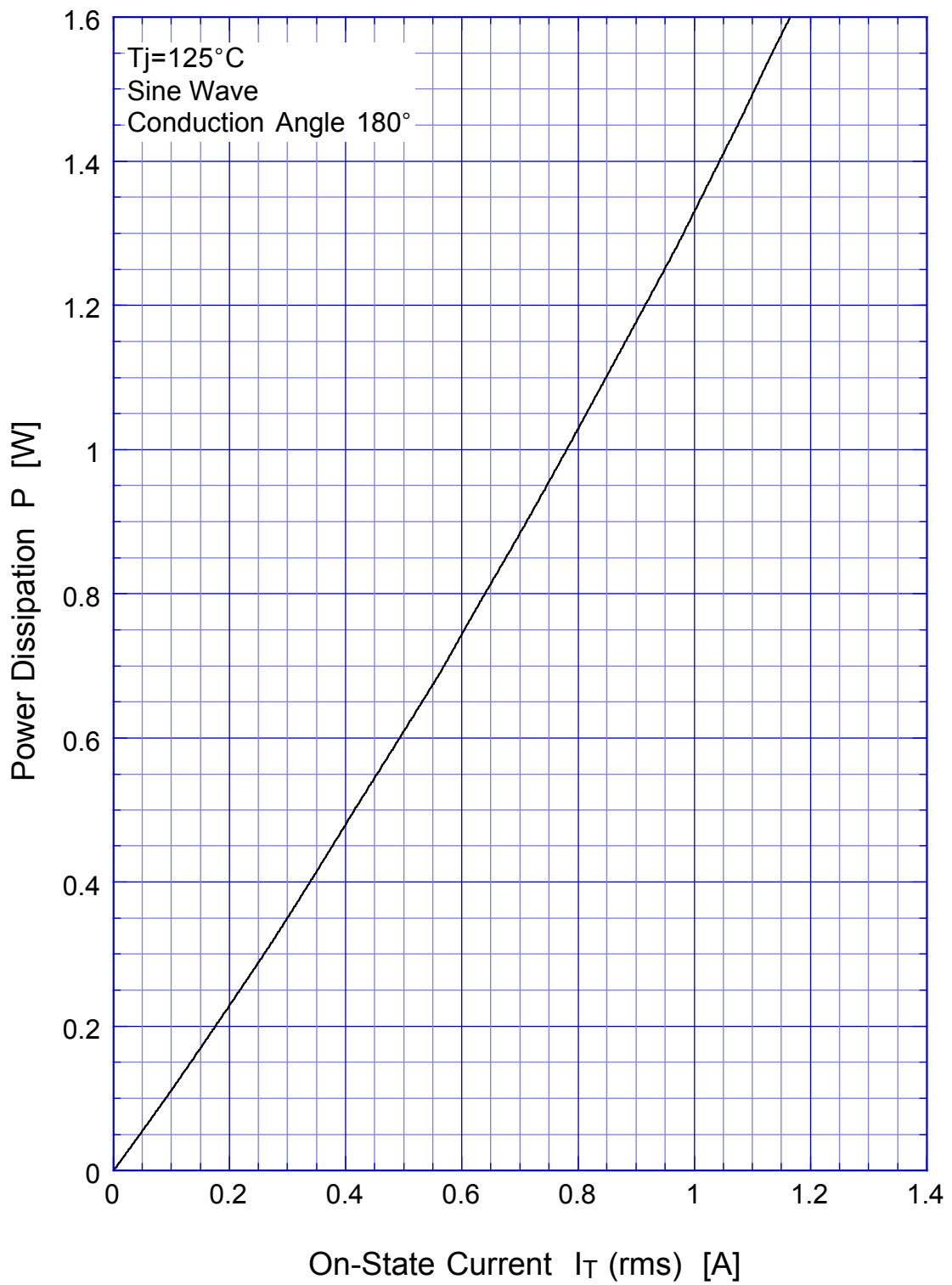


K1V(A)10

K1V(A)11

K1V(A)12

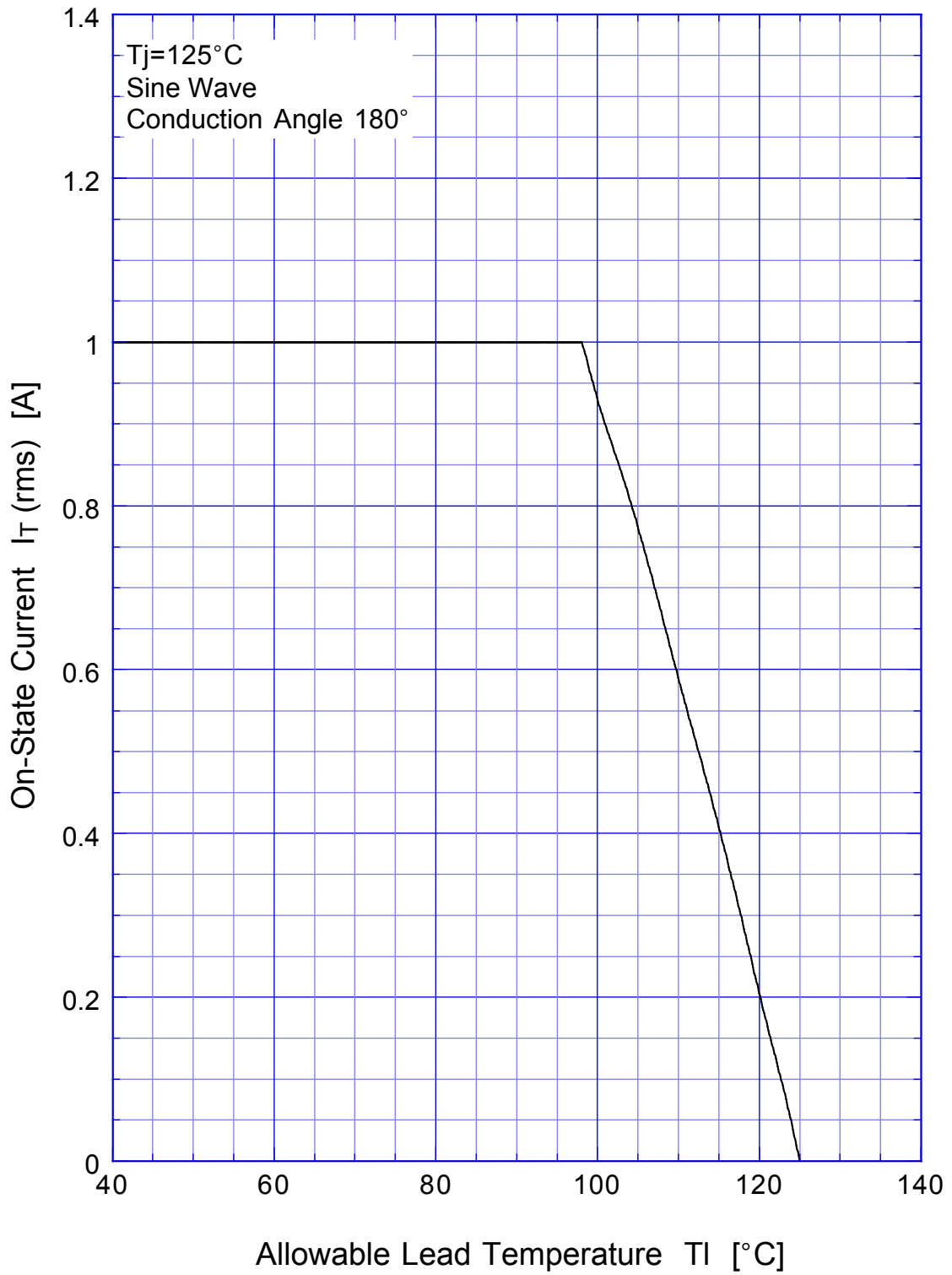
Power Dissipation



K1V(A)10

K1V(A)11

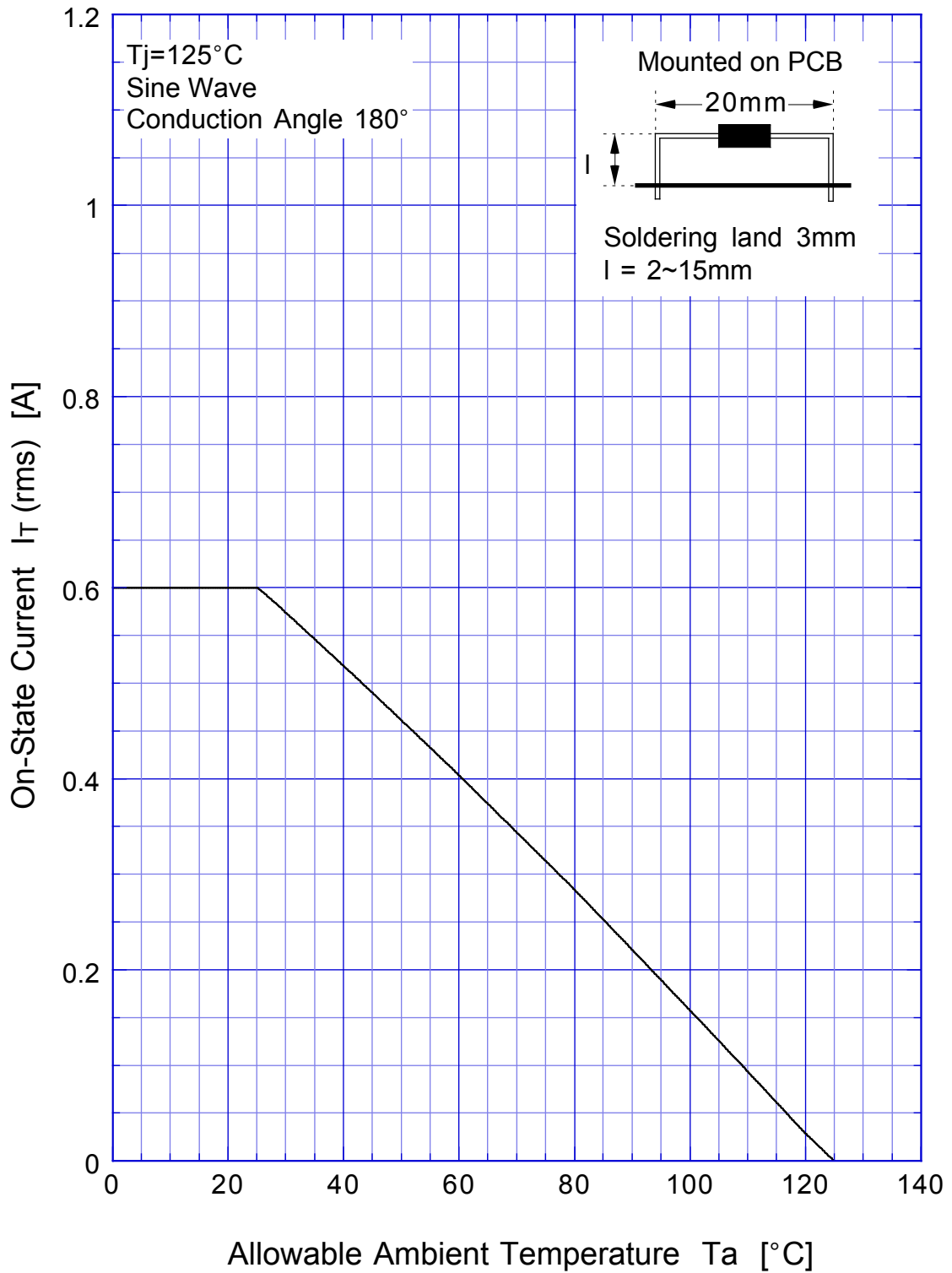
K1V(A)12 Maximum Lead Temperature



K1V(A)10

K1V(A)11

K1V(A)12 Maximum Ambient Temperature

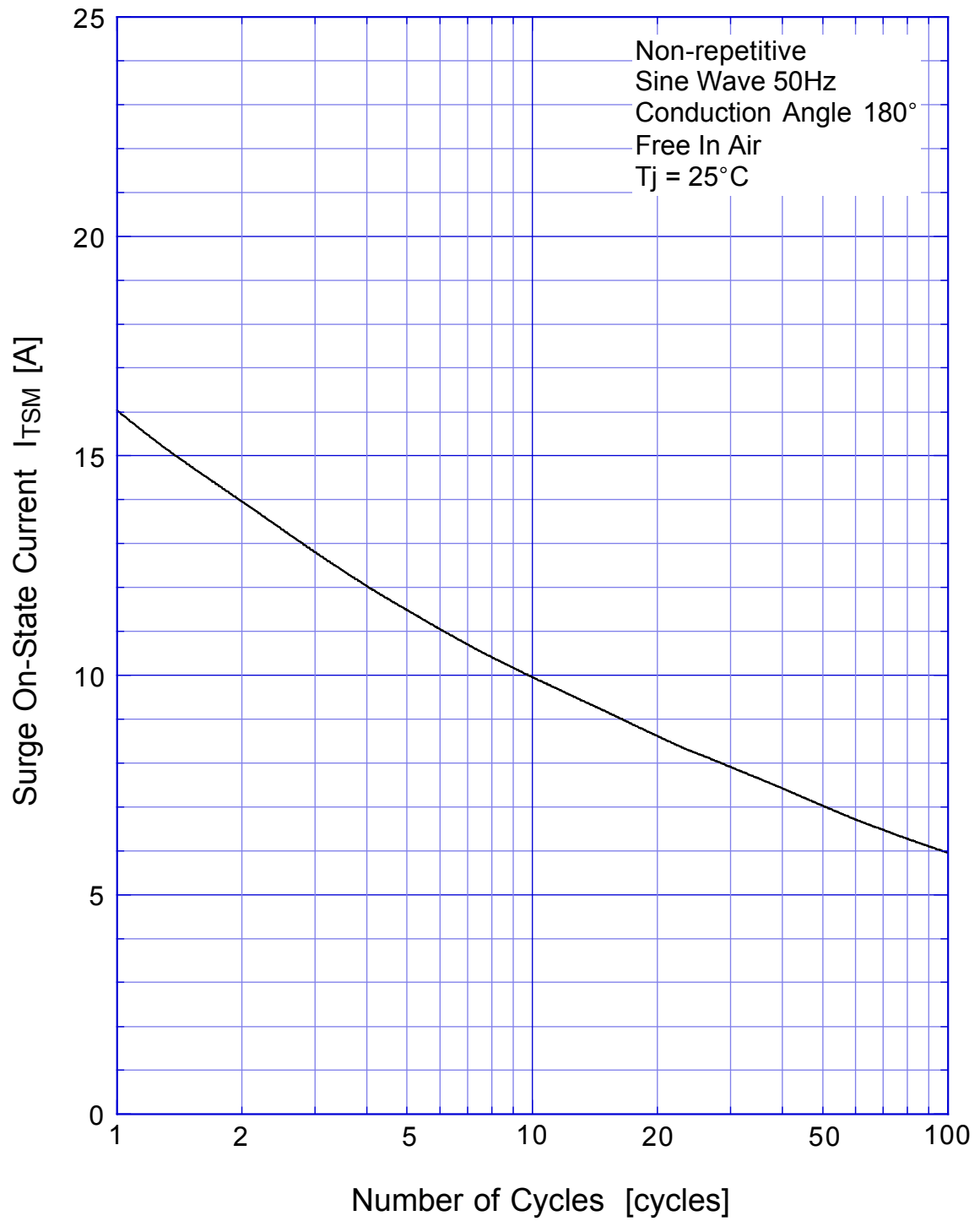


K1V(A)10

K1V(A)11

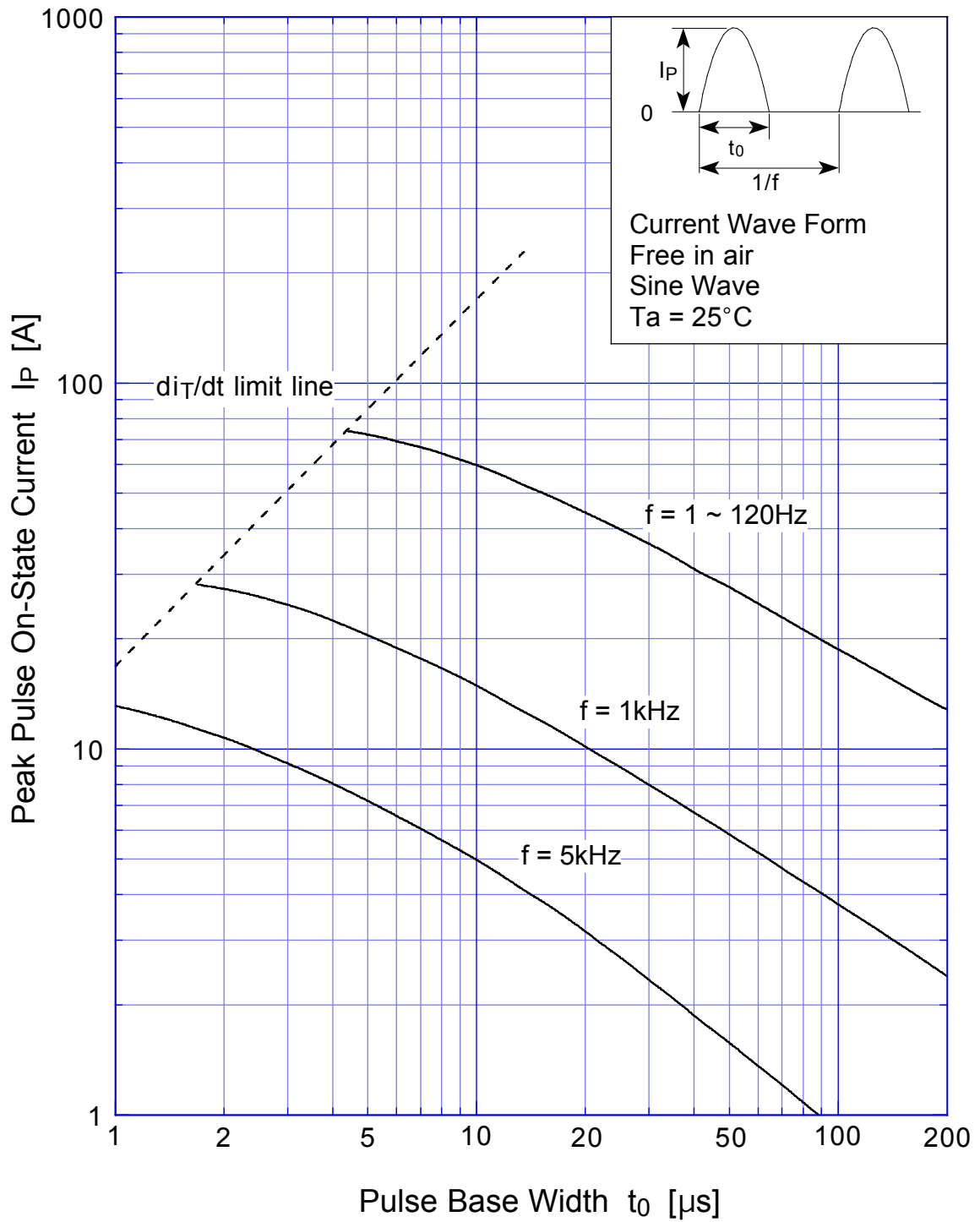
K1V(A)12

Maximum Surge On-State Current



K1V(A)10
K1V(A)11
K1V(A)12

Pulse On-State Current Rating

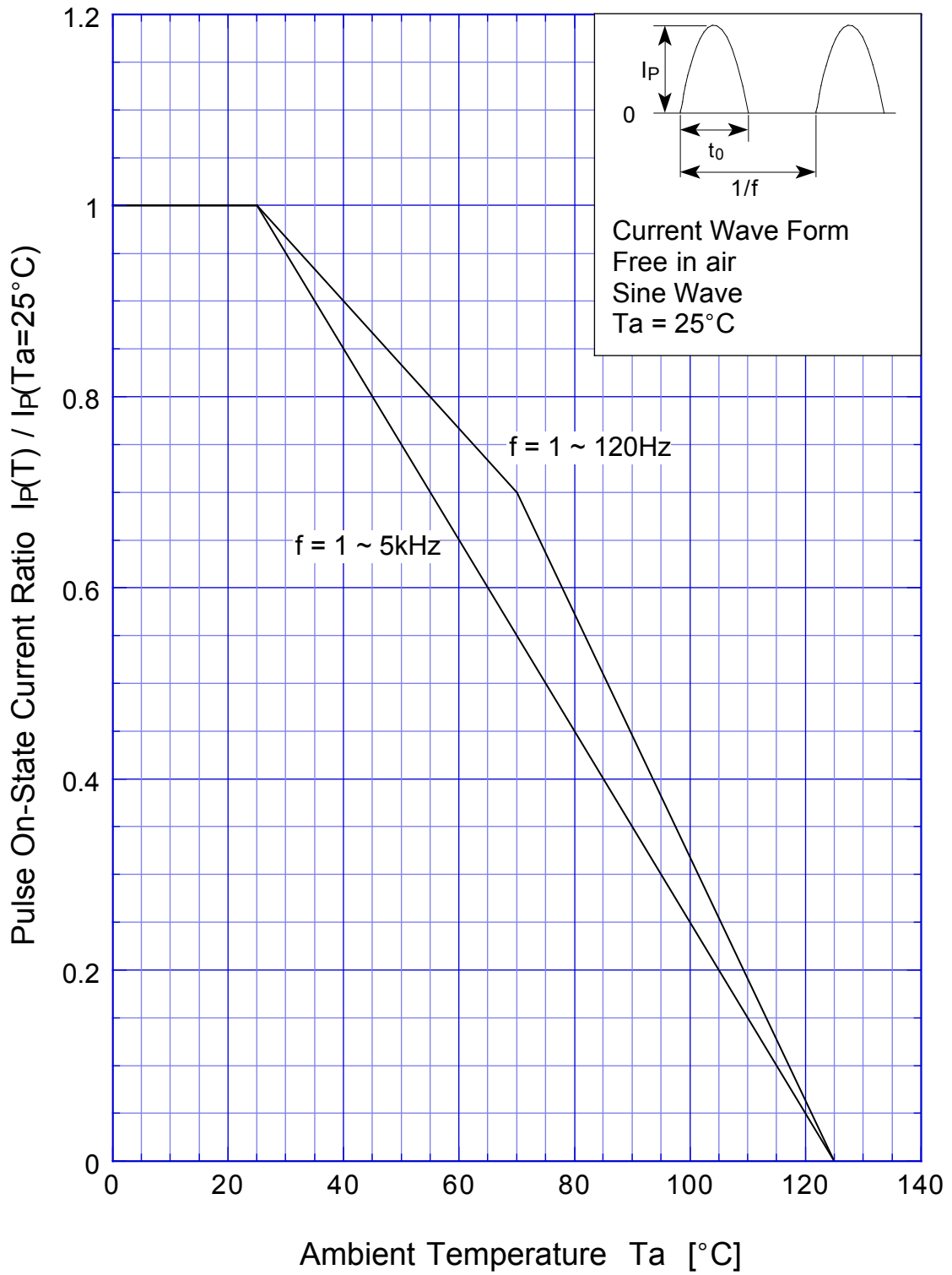


K1V(A)10

K1V(A)11

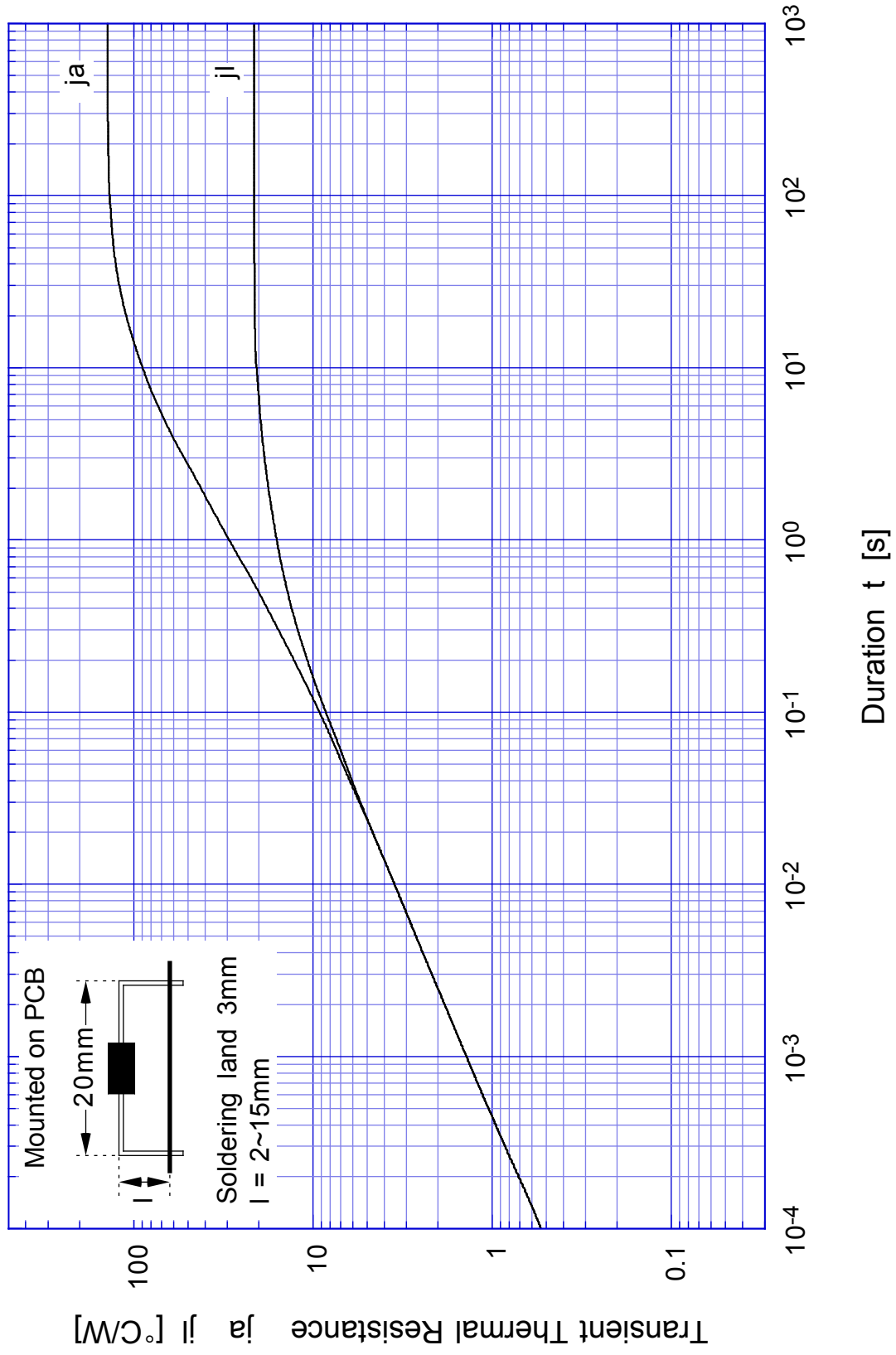
K1V(A)12

Pulse On-State Current Derating



K1V(A)10
K1V(A)11
K1V(A)12

Transient Thermal Resistance



K1V(A)10

K1V(A)11

K1V(A)12

Breakover Voltage - Junction Temperature

